# TC7SZ02FU

#### 1. Functional Description

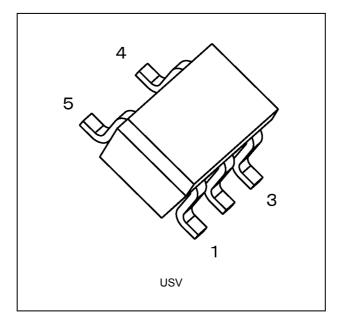
2-Input NOR Gate

#### 2. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C (Note 2)
- (3) High output current:  $\pm 24$  mA (min) at V<sub>CC</sub> = 3.0 V
- (4) Super high speed operation:  $t_{pd}$  = 2.4 ns (typ.) at V<sub>CC</sub> = 5.0 V, C<sub>L</sub> = 50 pF
- (5) Operation voltage range:  $V_{CC}$  = 1.65 to 5.5 V
- (6) 5.5 V tolerant inputs
- (7) 5.5 V power down protection output
- (8) Matches the performance of TC74LCX series when operated at  $3.3 \text{ V} V_{CC}$
- Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

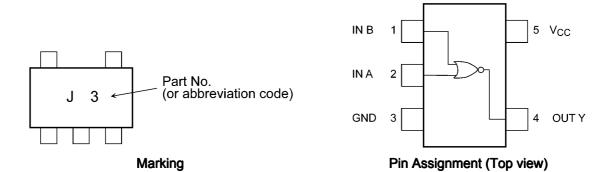
Note 2: For devices with the ordering part number ending in J(CT.  $T_{opr}$  = -40 to 85 °C for the other devices.

#### 3. Packaging



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### 4. Marking and Pin Assignment



#### 5. IEC Logic Symbol



#### 6. Truth Table

| А | В | Y |
|---|---|---|
| L | L | Н |
| L | Н | L |
| Н | L | L |
| Н | Н | L |

#### 7. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25$ °C)

| Characteristics                 | Symbol           | Note     | Rating                        | Unit |
|---------------------------------|------------------|----------|-------------------------------|------|
| Supply voltage                  | V <sub>CC</sub>  |          | -0.5 to 6.0                   | V    |
| Input voltage                   | V <sub>IN</sub>  |          | -0.5 to 6.0                   | V    |
| DC output voltage               | V <sub>OUT</sub> | (Note 1) | -0.5 to 6.0                   | V    |
|                                 |                  | (Note 2) | -0.5 to V <sub>CC</sub> + 0.5 |      |
| Input diode current             | I <sub>IK</sub>  |          | -20                           | mA   |
| Output diode current            | I <sub>OK</sub>  | (Note 3) | -20                           | mA   |
| DC output current               | I <sub>OUT</sub> |          | ±50                           | mA   |
| V <sub>CC</sub> /ground current | I <sub>CC</sub>  |          | ±50                           | mA   |
| Power dissipation               | PD               |          | 200                           | mW   |
| Storage temperature             | T <sub>stg</sub> |          | -65 to 150                    | °C   |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $V_{CC}$  = 0 V

Note 2: High (H) or Low (L) state.  $I_{\mbox{OUT}}$  absolute maximum rating must be observed.

Note 3: V<sub>OUT</sub> < GND

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#### 8. Operating Ranges (Note)

| Characteristics          | Symbol           | Note     | Test Condition                               | Rating               | Unit |
|--------------------------|------------------|----------|--|----------------------|------|
| Supply voltage           | V <sub>CC</sub>  |          | —  | 1.65 to 5.5          | V    |
|                          |                  | (Note 1) | _  | 1.5 to 5.5           |      |
| Input voltage            | V <sub>IN</sub>  |          | _  | 0 to 5.5             | V    |
| Output voltage           | V <sub>OUT</sub> | (Note 2) | —  | 0 to 5.5             | V    |
|                          |                  | (Note 3) | _  | 0 to V <sub>CC</sub> |      |
| Operating temperature    | T <sub>opr</sub> | (Note 4) | —  | -40 to 125           | °C   |
|                          |                  | (Note 5) | _  | -40 to 85            |      |
| Input rise and fall time | dt/dv            |          | $V_{CC}$ = 1.8 $\pm$ 0.15 V, 2.5 $\pm$ 0.2 V | 0 to 20              | ns/V |
|                          |                  |          | $V_{CC}$ = 3.3 ± 0.3 V                       | 0 to 10              |      |
|                          |                  |          | $V_{CC}$ = 5.0 ± 0.5 V                       | 0 to 5               |      |

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

Note 1: Data retention only

Note 2: V<sub>CC</sub> = 0 V

Note 3: High (H) or Low (L) state.

Note 4: For devices with the ordering part number ending in J(CT.

Note 5: For devices except those with the ordering part number ending in J(CT.

#### 9. Electrical Characteristics

#### 9.1. DC Characteristics (Unless otherwise specified, Ta = 25 °C)

| Characteristics              | Symbol           | Test Condition                              |                           | V <sub>CC</sub> (V) | Min                 | Тур. | Мах                  | Unit |
|------------------------------|------------------|---|---------------------------|---------------------|---------------------|------|----------------------|------|
| High-level input voltage     | V <sub>IH</sub>  | _   |                           | 1.65 to<br>1.95     | $V_{CC} 	imes 0.88$ | _    | —                    | V    |
|                              |                  |   |                           | 2.3 to 5.5          | $V_{CC} 	imes 0.75$ | _    | —                    |      |
| Low-level input voltage      | VIL              | —   |                           | 1.65 to<br>1.95     | _                   | _    | $V_{CC} \times 0.12$ | V    |
|                              |                  |   |                           | 2.3 to 5.5          | _                   |      | $V_{CC} \times 0.25$ |      |
| High-level output voltage    | V <sub>OH</sub>  | V <sub>IN</sub> = V <sub>IL</sub>           | I <sub>OH</sub> = -100 μA | 1.65                | 1.55                | 1.65 | —                    | V    |
|                              |                  |   |                           | 2.3                 | 2.2                 | 2.3  | —                    |      |
|                              |                  |   |                           | 3.0                 | 2.9                 | 3.0  | —                    |      |
|                              |                  |   |                           | 4.5                 | 4.4                 | 4.5  | —                    |      |
|                              |                  |   | I <sub>OH</sub> = -8 mA   | 2.3                 | 1.9                 | 2.15 | —                    |      |
|                              |                  |   | I <sub>OH</sub> = -16 mA  | 3.0                 | 2.4                 | 2.8  | —                    |      |
|                              |                  |   | I <sub>OH</sub> = -24 mA  | 3.0                 | 2.3                 | 2.68 | —                    |      |
|                              |                  |   | I <sub>OH</sub> = -32 mA  | 4.5                 | 3.8                 | 4.2  | —                    |      |
| Low-level output voltage     | V <sub>OL</sub>  | $V_{IN} = V_{IH} \text{ or } V_{IL}$        | I <sub>OL</sub> = 100 μA  | 1.65                | _                   | 0.0  | 0.1                  | V    |
|                              |                  |   |                           | 2.3                 | _                   | 0.0  | 0.1                  |      |
|                              |                  |   |                           | 3.0                 | _                   | 0.0  | 0.1                  |      |
|                              |                  |   |                           | 4.5                 | _                   | 0.0  | 0.1                  |      |
|                              |                  |   | I <sub>OL</sub> = 8 mA    | 2.3                 | _                   | 0.1  | 0.3                  |      |
|                              |                  |   | I <sub>OL</sub> = 16 mA   | 3.0                 | —                   | 0.15 | 0.4                  |      |
|                              |                  |   | I <sub>OL</sub> = 24 mA   | 3.0                 | _                   | 0.22 | 0.55                 |      |
|                              |                  |   | I <sub>OL</sub> = 32 mA   | 4.5                 | _                   | 0.22 | 0.55                 |      |
| Input leakage current        | I <sub>IN</sub>  | V <sub>IN</sub> = 5.5 V or GND              |                           | 0 to 5.5            | _                   | _    | ±1.0                 | μΑ   |
| Power-OFF leakage<br>current | I <sub>OFF</sub> | V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V |                           |                     | —                   | _    | 1                    | μA   |
| Quiescent supply current     | I <sub>CC</sub>  | V <sub>IN</sub> = V <sub>CC</sub> or GND    | $V_{IN} = V_{CC}$ or GND  |                     | _                   | _    | 2                    | μA   |

## 9.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

| Characteristics           | Symbol           | Test Condition                              | on                        | V <sub>CC</sub> (V) | Min                 | Max                  | Unit |
|---------------------------|------------------|---|---------------------------|---------------------|---------------------|----------------------|------|
| High-level input voltage  | V <sub>IH</sub>  | _   |                           | 1.65 to<br>1.95     | $V_{CC} 	imes 0.88$ | —                    | V    |
|                           |                  |   |                           | 2.3 to 5.5          | $V_{CC} 	imes 0.75$ | _                    |      |
| Low-level input voltage   | V <sub>IL</sub>  | _   |                           | 1.65 to<br>1.95     | —                   | $V_{CC} 	imes 0.12$  | V    |
|                           |                  |   |                           | 2.3 to 5.5          | —                   | $V_{CC} \times 0.25$ |      |
| High-level output voltage | V <sub>OH</sub>  | $V_{IN} = V_{IL}$                           | I <sub>OH</sub> = -100 μA | 1.65                | 1.55                | _                    | V    |
|                           |                  |   |                           | 2.3                 | 2.2                 | _                    |      |
|                           |                  |   |                           | 3.0                 | 2.9                 | _                    |      |
|                           |                  |   |                           | 4.5                 | 4.4                 | _                    |      |
|                           |                  |   | I <sub>OH</sub> = -8 mA   | 2.3                 | 1.9                 | _                    |      |
|                           |                  |   | I <sub>OH</sub> = -16 mA  | 3.0                 | 2.4                 | _                    |      |
|                           |                  |   | I <sub>OH</sub> = -24 mA  | 3.0                 | 2.3                 | _                    |      |
|                           |                  |   | I <sub>OH</sub> = -32 mA  | 4.5                 | 3.8                 | _                    |      |
| Low-level output voltage  | V <sub>OL</sub>  | $V_{IN} = V_{IH} \text{ or } V_{IL}$        | I <sub>OL</sub> = 100 μA  | 1.65                | _                   | 0.1                  | V    |
|                           |                  |   |                           | 2.3                 | _                   | 0.1                  |      |
|                           |                  |   |                           | 3.0                 | _                   | 0.1                  |      |
|                           |                  |   |                           | 4.5                 | _                   | 0.1                  |      |
|                           |                  |   | I <sub>OL</sub> = 8 mA    | 2.3                 | _                   | 0.3                  |      |
|                           |                  |   | I <sub>OL</sub> = 16 mA   | 3.0                 | _                   | 0.4                  |      |
|                           |                  |   | I <sub>OL</sub> = 24 mA   | 3.0                 | _                   | 0.55                 |      |
|                           |                  |   | I <sub>OL</sub> = 32 mA   | 4.5                 | _                   | 0.55                 |      |
| Input leakage current     | I <sub>IN</sub>  | V <sub>IN</sub> = 5.5 V or GND              |                           | 0 to 5.5            | _                   | ±10.0                | μA   |
| Power-OFF leakage current | I <sub>OFF</sub> | V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V |                           | 0                   | _                   | 10                   | μA   |
| Quiescent supply current  | I <sub>CC</sub>  | V <sub>IN</sub> = V <sub>CC</sub> or GND    |                           | 5.5                 | _                   | 20                   | μA   |

## 9.3. DC Characteristics (Note) (Unless otherwise specified, $T_a = -40$ to 125 °C)

| Characteristics           | Symbol           | Test Condition                              | on                        | V <sub>CC</sub> (V) | Min                 | Max                  | Unit |
|---------------------------|------------------|---|---------------------------|---------------------|---------------------|----------------------|------|
| High-level input voltage  | V <sub>IH</sub>  | _   |                           | 1.65 to<br>1.95     | $V_{CC} 	imes 0.88$ | —                    | V    |
|                           |                  |   |                           | 2.3 to 5.5          | $V_{CC} 	imes 0.75$ | _                    |      |
| Low-level input voltage   | V <sub>IL</sub>  | _   |                           | 1.65 to<br>1.95     | —                   | $V_{CC} 	imes 0.12$  | V    |
|                           |                  |   |                           | 2.3 to 5.5          | _                   | $V_{CC} \times 0.25$ |      |
| High-level output voltage | V <sub>OH</sub>  | V <sub>IN</sub> = V <sub>IL</sub>           | I <sub>OH</sub> = -100 μA | 1.65                | 1.55                | _                    | V    |
|                           |                  |   |                           | 2.3                 | 2.2                 | _                    |      |
|                           |                  |   |                           | 3.0                 | 2.9                 | _                    |      |
|                           |                  |   |                           | 4.5                 | 4.4                 | _                    |      |
|                           |                  |   | I <sub>OH</sub> = -8 mA   | 2.3                 | 1.7                 | _                    |      |
|                           |                  |   | I <sub>OH</sub> = -16 mA  | 3.0                 | 2.2                 | _                    |      |
|                           |                  |   | I <sub>OH</sub> = -24 mA  | 3.0                 | 2.0                 | _                    |      |
|                           |                  |   | I <sub>OH</sub> = -32 mA  | 4.5                 | 3.4                 | _                    |      |
| Low-level output voltage  | V <sub>OL</sub>  | $V_{IN} = V_{IH} \text{ or } V_{IL}$        | I <sub>OL</sub> = 100 μA  | 1.65                | _                   | 0.1                  | V    |
|                           |                  |   |                           | 2.3                 | _                   | 0.1                  |      |
|                           |                  |   |                           | 3.0                 | _                   | 0.1                  |      |
|                           |                  |   |                           | 4.5                 | _                   | 0.1                  |      |
|                           |                  |   | I <sub>OL</sub> = 8 mA    | 2.3                 | _                   | 0.45                 |      |
|                           |                  |   | I <sub>OL</sub> = 16 mA   | 3.0                 | _                   | 0.6                  |      |
|                           |                  |   | I <sub>OL</sub> = 24 mA   | 3.0                 | _                   | 0.8                  |      |
|                           |                  |   | I <sub>OL</sub> = 32 mA   | 4.5                 | _                   | 0.8                  |      |
| Input leakage current     | I <sub>IN</sub>  | V <sub>IN</sub> = 5.5 V or GND              |                           | 0 to 5.5            | _                   | ±20.0                | μA   |
| Power-OFF leakage current | I <sub>OFF</sub> | V <sub>IN</sub> or V <sub>OUT</sub> = 5.5 V |                           | 0                   | _                   | 100                  | μA   |
| Quiescent supply current  | I <sub>CC</sub>  | V <sub>IN</sub> = V <sub>CC</sub> or GND    |                           | 5.5                 | _                   | 200                  | μA   |

Note: For devices with the ordering part number ending in J(CT.

#### 9.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

| Characteristics        | Symbol                             | Note     | Test<br>Condition      | V <sub>CC</sub> (V)              | C <sub>L</sub> (pF) | Min | Тур. | Max | Unit |
|------------------------|------------------------------------|----------|------------------------|----------------------------------|---------------------|-----|------|-----|------|
| Propagation delay time | t <sub>PLH</sub> ,t <sub>PHL</sub> |          | $R_L = 1 M\Omega$      | $\textbf{1.8} \pm \textbf{0.15}$ | 15                  | 2.0 | 4.4  | 9.5 | ns   |
|                        |                                    |          |                        | $\textbf{2.5}\pm\textbf{0.2}$    |                     | 0.8 | 2.9  | 6.5 |      |
|                        |                                    |          |                        | $\textbf{3.3}\pm\textbf{0.3}$    |                     | 0.5 | 2.3  | 4.5 |      |
|                        |                                    |          |                        | $5.0\pm0.5$                      |                     | 0.5 | 1.9  | 3.9 |      |
|                        |                                    |          | R <sub>L</sub> = 500 Ω | $\textbf{3.3}\pm\textbf{0.3}$    | 50                  | 1.5 | 2.9  | 5.0 | ns   |
|                        |                                    |          |                        | $5.0\pm0.5$                      |                     | 0.8 | 2.4  | 4.3 |      |
| Input capacitance      | C <sub>IN</sub>                    |          | —                      | 0 to 5.5                         | _                   | _   | 4    | _   | pF   |
| Power dissipation      | C <sub>PD</sub>                    | (Note 1) | —                      | 3.3                              | _                   | _   | 23   | _   | pF   |
| capacitance            |                                    |          |                        | 5.5                              |                     | _   | 30   | _   |      |

Note 1:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.  $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

# 9.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

| Characteristics        | Symbol                             | Test Condition         | V <sub>CC</sub> (V)           | C <sub>L</sub> (pF) | Min | Max  | Unit |
|------------------------|------------------------------------|------------------------|-------------------------------|---------------------|-----|------|------|
| Propagation delay time | t <sub>PLH</sub> ,t <sub>PHL</sub> | $R_L = 1 M\Omega$      | $1.8\pm0.15$                  | 15                  | 2.0 | 10.0 | ns   |
|                        |                                    |                        | $2.5\pm0.2$                   |                     | 0.8 | 7.0  |      |
|                        |                                    |                        | $\textbf{3.3}\pm\textbf{0.3}$ |                     | 0.5 | 4.7  |      |
|                        |                                    |                        | $5.0\pm0.5$                   | ]                   | 0.5 | 4.1  |      |
|                        |                                    | R <sub>L</sub> = 500 Ω | $3.3\pm0.3$                   | 50                  | 1.5 | 5.2  | ns   |
|                        |                                    |                        | $5.0\pm0.5$                   |                     | 0.8 | 4.5  |      |

#### 9.6. AC Characteristics (Note) (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

| Characteristics        | Symbol                             | Test Condition         | V <sub>CC</sub> (V)           | C <sub>L</sub> (pF) | Min | Max  | Unit |
|------------------------|------------------------------------|------------------------|-------------------------------|---------------------|-----|------|------|
| Propagation delay time | t <sub>PLH</sub> ,t <sub>PHL</sub> | $R_L = 1 M\Omega$      | $1.8\pm0.15$                  | 15                  | 2.0 | 11.0 | ns   |
|                        |                                    |                        | $2.5\pm0.2$                   |                     | 0.8 | 8.0  |      |
|                        |                                    |                        | $3.3\pm0.3$                   |                     | 0.5 | 5.5  |      |
|                        |                                    |                        | $5.0\pm0.5$                   |                     | 0.5 | 5.0  |      |
|                        |                                    | R <sub>L</sub> = 500 Ω | $\textbf{3.3}\pm\textbf{0.3}$ | 50                  | 1.5 | 6.0  | ns   |
|                        |                                    |                        | $5.0\pm0.5$                   |                     | 0.8 | 5.0  |      |

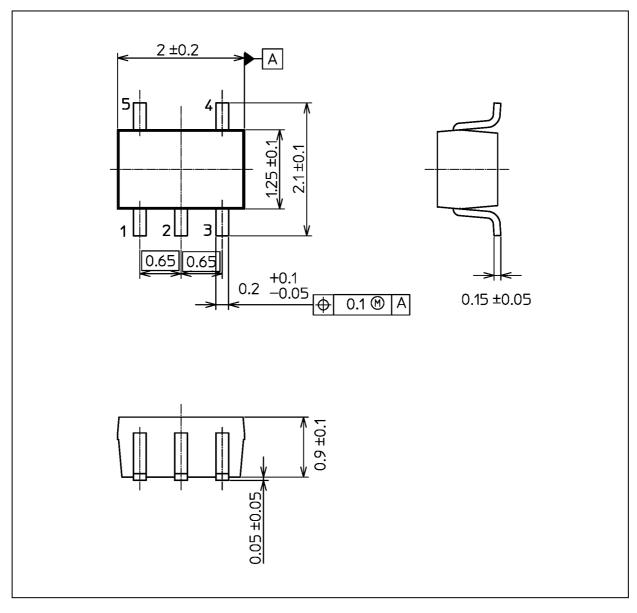
Note: For devices with the ordering part number ending in J(CT.



#### **Package Dimensions**

TC7SZ02FU

Unit: mm



Weight: 0.006 g (typ.)

|                | Package Name(s) |
|----------------|-----------------|
| JEDEC: SOT-353 |                 |
| Nickname: USV  |                 |

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